

vPolyTan™ Hermetically Sealed Polymer Surface-Mount Chip Capacitors, Low ESR



LINKS TO ADDITIONAL RESOURCES



3D Models



Models



Calculators

PERFORMANCE / ELECTRICAL CHARACTERISTICS

Operating Temperature: -55 °C to +125 °C
(above 105 °C, additional voltage derating is required)

Capacitance Range: 15 µF to 470 µF

Capacitance Tolerance: ± 20 %

Voltage Rating: 16 V_{DC} to 75 V_{DC}

FEATURES

- Ultra low ESR conductive polymer cathode
- Ultra low DC leakage < 0.05 CV
- High reliability processing including:
 - 100 % hermiticity tested metal case
 - 100 % surge current test
 - accelerated voltage conditioning
 - thermal shock
 - MIL-PRF-39003 style qualification
- High ripple current capability
- Stable capacitance in operating temperature range
- High frequency capacitance retention
- No wear out effect
- PATENT(S): www.vishay.com/patents
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912



Note

* This datasheet provides information about parts that are RoHS-compliant and / or parts that are non RoHS-compliant. For example, parts with lead (Pb) terminations are not RoHS-compliant. Please see the information / tables in this datasheet for details

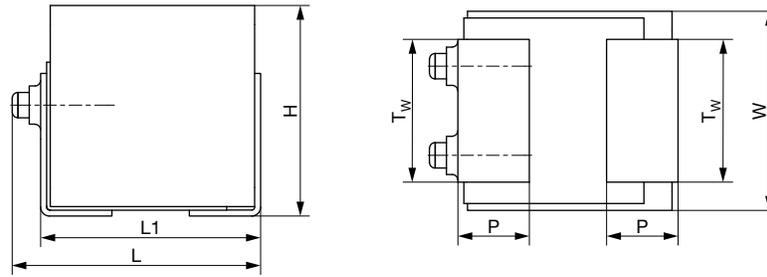
APPLICATIONS

- Aerospace and hi-rel applications
- Switch mode and point of load power supply

ORDERING INFORMATION								
T27	D	226	M	063	E	S	A	025
TYPE	CASE CODE	CAPACITANCE	CAPACITANCE TOLERANCE	DC VOLTAGE RATING	TERMINATION / PACKAGING	RELIABILITY LEVEL	SURGE CURRENT LEVEL	ESR
		This is expressed in picofarads. The first two digits are the significant figures. The third is the number of zeros to follow.	M = ± 20 %	This is expressed in volts. To complete the three-digit block, zeros precede the voltage rating.	Sn / Pb solder E = 7" (178 mm) reel L = 7" (178 mm), 1/2 reel R = 7" (178 mm), partial reel 100 % tin C = 7" (178 mm), reel H = 7" (178 mm), 1/2 reel U = 7" (178 mm), partial reel	S = 40 h burn-in	A = 10 cycles at +25 °C B = 10 cycles at -55 °C / +85 °C	Maximum 100 kHz ESR in mΩ

PATENT(S): www.vishay.com/patents

This Vishay product is protected by one or more United States and international patents.

DIMENSIONS in inches [millimeters]


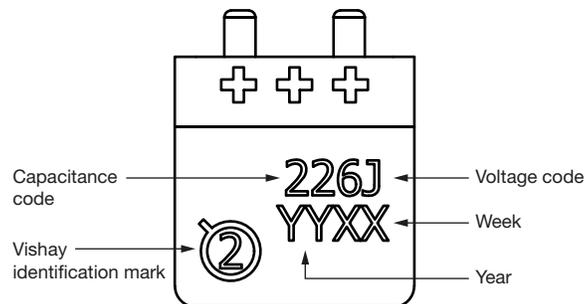
CASE CODE	L (MAX.)	L1	W	H	P	Tw
D	0.374 [9.5]	0.303 ± 0.008 [7.7 ± 0.2]	0.275 ± 0.008 [7.0 ± 0.2]	0.291 ± 0.008 [7.4 ± 0.2]	0.098 ± 0.008 [2.5 ± 0.2]	0.197 ± 0.008 [5.0 ± 0.2]

RATINGS AND CASE CODES (ESR, mΩ)

μF	16 V	25 V	35 V	50 V	63 V	75 V
15					D (100) ⁽¹⁾	D (100) ⁽¹⁾
22				D (100) ⁽¹⁾	D (100) ⁽¹⁾	D (100) ⁽¹⁾
33				D (100) ⁽¹⁾	D (100) ⁽¹⁾	
47			D (70) ⁽¹⁾	D (100)		
150			D (100) ⁽¹⁾			
220		D (55) ⁽¹⁾				
330	D (25)					
470	D (25) ⁽¹⁾					

Note

⁽¹⁾ Currently in development, contact factory for availability

MARKING


VOLTAGE NOMINAL	VOLTAGE CODE
16	C
20	D
25	E
35	V
50	H
63	J
75	S

Notes

- Marking shows discrete capacitor rating
- Capacitance code is expressed in picofarads. The first two digits are the significant figures. The third is the number of zeros to follow



STANDARD RATINGS								
CAPACITANCE (μ F)	CASE CODE	PART NUMBER	MAX. DCL AT 25 °C (μ A)	MAX. DF AT 25 °C 120 Hz (%)	MAX. ESR AT +25 °C 100 kHz (m Ω)	MAX. RIPPLE 100 kHz I _{RMS} (A)	HIGH TEMPERATURE LOAD	
							TEMPERATURE (°C)	TIME (h)
16 V_{DC} AT +105 °C, 10 V_{DC} AT +125 °C								
330	D	T27D337M016(1)(2)(3)025	264	12	25	4.899	125	2000
470	D ⁽¹⁾	T27D477M016(1)(2)(3)025	376	12	25	4.899	125	2000
25 V_{DC} AT +105 °C, 20 V_{DC} AT +125 °C								
220	D ⁽¹⁾	T27D227M025(1)(2)(3)055	275	12	55	3.303	125	2000
35 V_{DC} AT +105 °C, 25 V_{DC} AT +125 °C								
47	D ⁽¹⁾	T27D476M035(1)(2)(3)070	82	12	70	2.928	125	2000
150	D ⁽¹⁾	T27D157M035(1)(2)(3)100	263	12	100	2.449	125	2000
50 V_{DC} AT +105 °C, 33 V_{DC} AT +125 °C								
22	D ⁽¹⁾	T27D226M050(1)(2)(3)100	55	12	100	2.449	125	2000
33	D ⁽¹⁾	T27D336M050(1)(2)(3)100	83	12	100	2.449	125	2000
47	D	T27D476M050(1)(2)(3)100	118	12	100	2.449	125	2000
63 V_{DC} AT +105 °C, 43 V_{DC} AT +125 °C								
15	D ⁽¹⁾	T27D156M063(1)(2)(3)100	47	12	100	2.449	125	2000
22	D ⁽¹⁾	T27D226M063(1)(2)(3)100	69	12	100	2.449	125	2000
33	D ⁽¹⁾	T27D336M063(1)(2)(3)100	104	12	100	2.449	125	2000
75 V_{DC} AT +105 °C, 50 V_{DC} AT +125 °C								
15	D ⁽¹⁾	T27D156M075(1)(2)(3)100	56	12	100	2.449	125	2000
22	D ⁽¹⁾	T27D226M075(1)(2)(3)100	83	12	100	2.449	125	2000

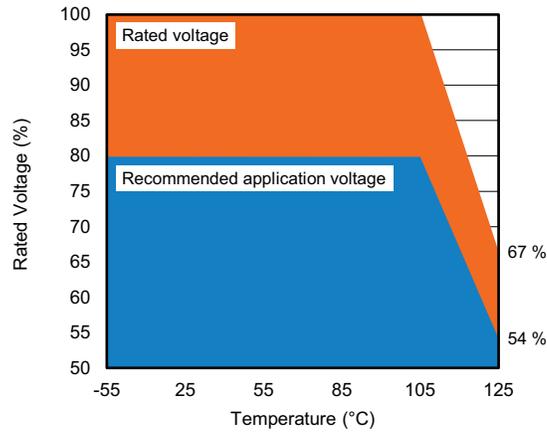
Notes

- Part number definitions:
 - (1) Termination and packaging: E, L, C, H
 - (2) Reliability level: S
 - (3) Surge current: A, B
- (¹) Rating in development, contact factory for availability

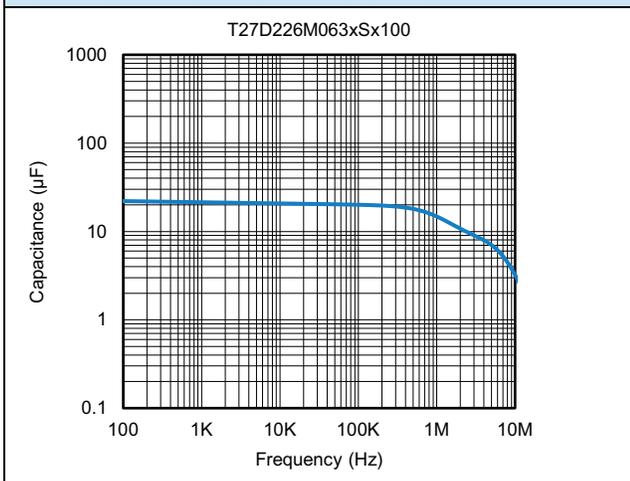
RECOMMENDED VOLTAGE DERATING GUIDELINES			
CAPACITOR VOLTAGE RATING AT -55 °C TO +105 °C	CAPACITOR VOLTAGE RATING AT +105 °C TO +125 °C	OPERATING VOLTAGES FOR TEMPERATURES AT -55 °C TO +105 °C	OPERATING VOLTAGES FOR TEMPERATURES AT +105 °C TO +125 °C
16	10.7	12.8	8.6
25	16.8	20	13.4
35	23.5	28	18.8
50	33.5	40	26.8
63	42	50.4	33.8
75	50	60	40



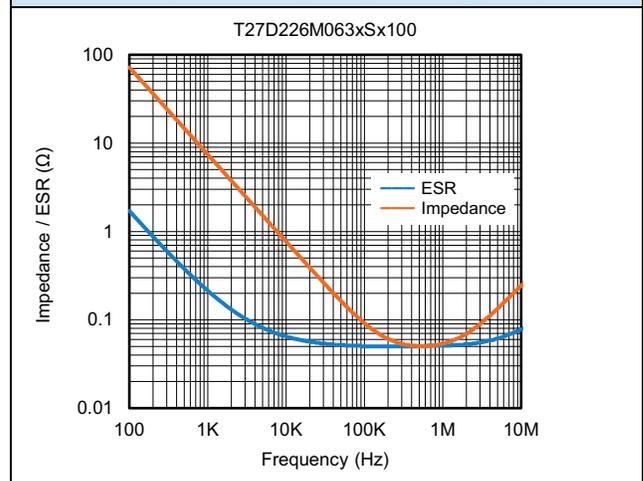
RECOMMENDED TEMPERATURE DERATING



CAPACITANCE VS. FREQUENCY



IMPEDANCE AND ESR VS. FREQUENCY



POWER DISSIPATION

CASE CODE	MAXIMUM PERMISSIBLE POWER DISSIPATION (W) AT ≤ +45 °C IN FREE AIR
D	0.6

STANDARD PACKAGING QUANTITY

CASE CODE	7" FULL REEL	7" HALF REEL
D	100	50



PERFORMANCE CHARACTERISTICS: MIL-PRF-39003 STYLE					
GROUP	ITEM	CONDITION		POST TEST PERFORMANCE	
I	Shock (specified pulse)	MIL-STD-202-213, condition I, 100 g peak		Capacitance change	Within ± 10 % of initial value
				Dissipation factor	Within initial limit
				Leakage current	Shall not exceed 200 % of initial limit
	Vibration	MIL-STD-202-204, condition D, 10 Hz to 2000 Hz, 20 g peak		Capacitance change	Within ± 10 % of initial value
				Dissipation factor	Within initial limit
				Leakage current	Shall not exceed 200 % of initial limit
				There shall be no mechanical or visual damage to capacitors post-conditioning.	
	Salt atmosphere (corrosion)	MIL-STD-202-101, condition B		Capacitors shall be visually examined for evidence of corrosion or other defects that will affect life or serviceability.	
	Thermal shock	MIL-STD-202-107, condition B		Capacitance change	Within ± 20 % of initial value
				Dissipation factor	Within initial limit
				Leakage current	Shall not exceed 200 % of initial limit
	Immersion	MIL-STD-202-104, condition B		Capacitance change	Within ± 20 % of initial value
				Dissipation factor	Within initial limit
				Leakage current	Shall not exceed 200 % of initial limit
				Capacitors shall be visually examined for evidence of corrosion, mechanical damage, and obliteration of marking.	
II	Solderability	MIL-STD-202-208, condition B		After the test, the solderable surfaces shall be examined.	
	Resistance to solvents	MIL-STD-202-215		There shall be no evidence of mechanical damage and the marking shall remain legible.	
	Resistance to soldering heat	MIL-STD-202-210, condition J		Capacitance change	Within ± 20 % of initial value
				Dissipation factor	Within initial limit
				Leakage current	Shall not exceed 200 % of initial limit
	Moisture resistance	MIL-STD-202-106		Capacitance change	Within ± 10 % of initial value
				Dissipation factor	Within initial limit
				Leakage current	Shall not exceed 200 % of initial limit
There shall be no evidence of harmful corrosion, mechanical damage, or obliteration of marking.					
Sleeving	MIL-PRF-39003		The insulation resistance shall be 1000 MΩ, minimum.		
III	Stability at low and high temperatures	MIL-PRF-39003	-55 °C	Capacitance change	Within -20 % to +0 % of initial value
				Dissipation factor	Shall not exceed 150 % of initial limit
				Leakage current	n/a
			25 °C	Capacitance change	Within ± 20 % of initial value
				Dissipation factor	Within initial limit
				Leakage current	Within initial limit
			85 °C	Capacitance change	Within -0 % to +30 % of initial value
				Dissipation factor	Shall not exceed 150 % of initial
				Leakage current	Shall not exceed 1000 % of initial value
			125 °C	Capacitance change	Within -0 % to +40 % of initial value
				Dissipation factor	Shall not exceed 200 % of initial
				Leakage current	Shall not exceed 1250 % of initial limit
	Surge voltage	MIL-PRF-39003		Capacitance change	Within ± 10 % of initial value
			Dissipation factor	Within initial limit	
			Leakage current	Shall not exceed 200 % of initial limit	



PERFORMANCE CHARACTERISTICS: MIL-PRF-39003 STYLE

GROUP	ITEM	CONDITION	POST TEST PERFORMANCE	
IV	Life test at +125 °C	2000 h application of 2/3 rated voltage at 125 °C, MIL-STD-202-108	Capacitance change	Within ± 20 % of initial value
			Dissipation factor	Shall not exceed 150 % of initial
			Leakage current	Shall not exceed 125 % of initial limit
V	Life test at +85 °C	2000 h application of rated voltage at 85 °C, MIL-STD-202-108	Capacitance change	Within ± 20 % of initial value
			Dissipation factor	Shall not exceed 150 % of initial
			Leakage current	Shall not exceed 125 % of initial limit
VI	Shear test	AEC-Q200-006	Capacitance change	Within ± 20 % of initial value
			Dissipation factor	Within initial limit
			Leakage current	Shall not exceed 200 % of initial limit

PRODUCT INFORMATION

Polymer Guide	www.vishay.com/doc?40076
Moisture Sensitivity	www.vishay.com/doc?40135
Infographic	www.vishay.com/doc?48084
Sample Board	www.vishay.com/doc?48073
FAQ	
Frequently Asked Questions	www.vishay.com/doc?42106



Guide for Tantalum Solid Electrolyte Chip Capacitors With Polymer Cathode

INTRODUCTION

Tantalum electrolytic capacitors are the preferred choice in applications where volumetric efficiency, stable electrical parameters, high reliability, and long service life are primary considerations. The stability and resistance to elevated temperatures of the tantalum/tantalum oxide/manganese dioxide system make solid tantalum capacitors an appropriate choice for today's surface mount assembly technology.

Vishay Sprague has been a pioneer and leader in this field, producing a large variety of tantalum capacitor types for consumer, industrial, automotive, military, and aerospace electronic applications.

Tantalum is not found in its pure state. Rather, it is commonly found in a number of oxide minerals, often in combination with Columbium ore. This combination is known as "tantalite" when its contents are more than one-half tantalum. Important sources of tantalite include Australia, Brazil, Canada, China, and several African countries. Synthetic tantalite concentrates produced from tin slags in Thailand, Malaysia, and Brazil are also a significant raw material for tantalum production.

Electronic applications, and particularly capacitors, consume the largest share of world tantalum production. Other important applications for tantalum include cutting tools (tantalum carbide), high temperature super alloys, chemical processing equipment, medical implants, and military ordnance.

Vishay Sprague is a major user of tantalum materials in the form of powder and wire for capacitor elements and rod and sheet for high temperature vacuum processing.

THE BASICS OF TANTALUM CAPACITORS

Most metals form crystalline oxides which are non-protecting, such as rust on iron or black oxide on copper. A few metals form dense, stable, tightly adhering, electrically insulating oxides. These are the so-called "valve"metals and include titanium, zirconium, niobium, tantalum, hafnium, and aluminum. Only a few of these permit the accurate control of oxide thickness by electrochemical means. Of these, the most valuable for the electronics industry are aluminum and tantalum.

Capacitors are basic to all kinds of electrical equipment, from radios and television sets to missile controls and automobile ignitions. Their function is to store an electrical charge for later use.

Capacitors consist of two conducting surfaces, usually metal plates, whose function is to conduct electricity. They are separated by an insulating material or dielectric. The dielectric used in all tantalum electrolytic capacitors is tantalum pentoxide.

Tantalum pentoxide compound possesses high-dielectric strength and a high-dielectric constant. As capacitors are being manufactured, a film of tantalum pentoxide is applied to their electrodes by means of an electrolytic process. The film is applied in various thicknesses and at various voltages and although transparent to begin with, it takes on different colors as light refracts through it. This coloring occurs on the tantalum electrodes of all types of tantalum capacitors.

Rating for rating, tantalum capacitors tend to have as much as three times better capacitance/volume efficiency than aluminum electrolytic capacitors. An approximation of the capacitance/volume efficiency of other types of capacitors may be inferred from the following table, which shows the dielectric constant ranges of the various materials used in each type. Note that tantalum pentoxide has a dielectric constant of 26, some three times greater than that of aluminum oxide. This, in addition to the fact that extremely thin films can be deposited during the electrolytic process mentioned earlier, makes the tantalum capacitor extremely efficient with respect to the number of microfarads available per unit volume. The capacitance of any capacitor is determined by the surface area of the two conducting plates, the distance between the plates, and the dielectric constant of the insulating material between the plates.

COMPARISON OF CAPACITOR DIELECTRIC CONSTANTS	
DIELECTRIC	ϵ DIELECTRIC CONSTANT
Air or vacuum	1.0
Paper	2.0 to 6.0
Plastic	2.1 to 6.0
Mineral oil	2.2 to 2.3
Silicone oil	2.7 to 2.8
Quartz	3.8 to 4.4
Glass	4.8 to 8.0
Porcelain	5.1 to 5.9
Mica	5.4 to 8.7
Aluminum oxide	8.4
Tantalum pentoxide	26
Ceramic	12 to 400K

In the tantalum electrolytic capacitor, the distance between the plates is very small since it is only the thickness of the tantalum pentoxide film. As the dielectric constant of the tantalum pentoxide is high, the capacitance of a tantalum capacitor is high if the area of the plates is large:

$$C = \frac{\epsilon A}{t}$$

where

C = capacitance

ϵ = dielectric constant

A = surface area of the dielectric

t = thickness of the dielectric

Tantalum capacitors contain either liquid or solid electrolytes. In solid electrolyte capacitors, a dry material (manganese dioxide) forms the cathode plate. A tantalum lead is embedded in or welded to the pellet, which is in turn connected to a termination or lead wire. The drawings show the construction details of the surface mount types of tantalum capacitors shown in this catalog.

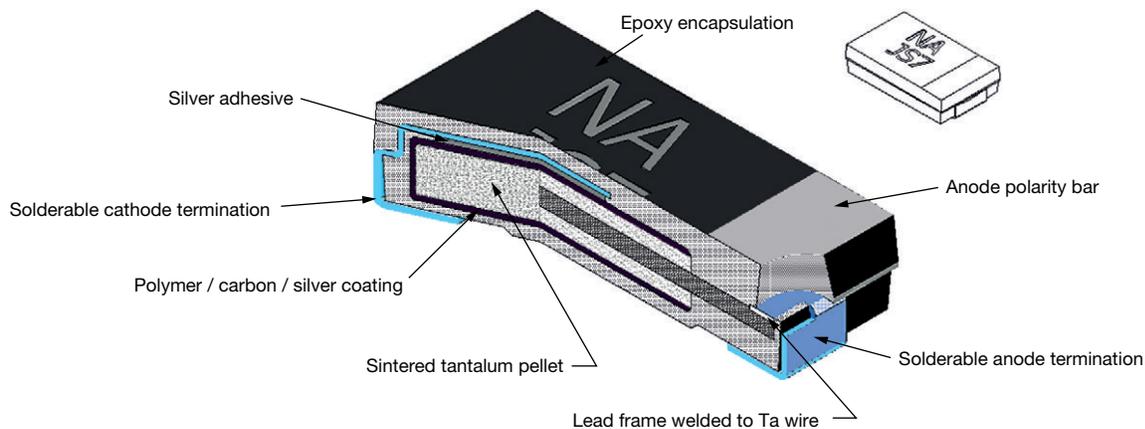
SOLID ELECTROLYTE POLYMER TANTALUM CAPACITORS

Solid electrolyte polymer capacitors utilize sintered tantalum pellets as anodes. Tantalum pentoxide dielectric layer is formed on the entire surface of anode, which is further impregnated with highly conductive polymer as cathode system.

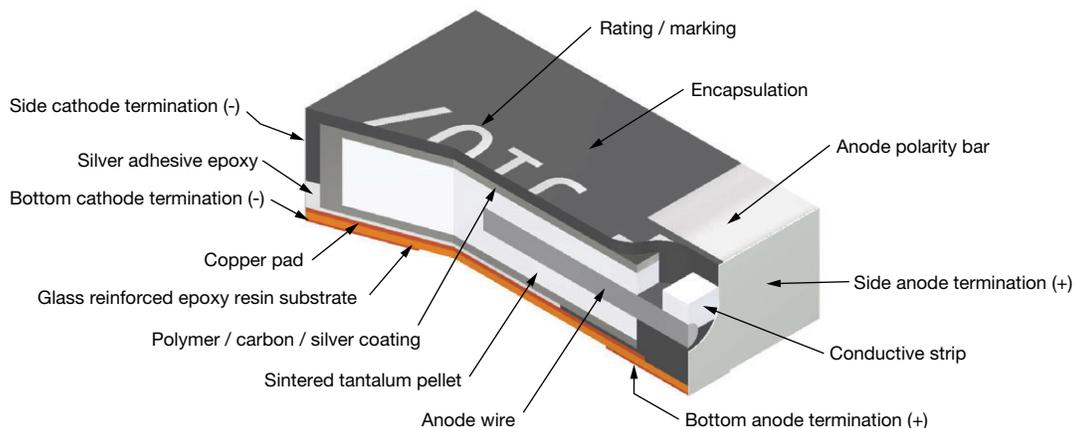
The conductive polymer layer is then coated with graphite, followed by a layer of metallic silver, which provides a conductive surface between the capacitor element and the outer termination (lead frame or other).

Molded chip polymer tantalum capacitor encases the element in plastic resins, such as epoxy materials. The molding compound has been selected to meet the requirements of UL 94 V-0 and outgassing requirements of ASTM E-595. After assembly, the capacitors are tested and inspected to assure long life and reliability. It offers excellent reliability and high stability for variety of applications in electronic devices. Usage of conductive polymer cathode system provides very low equivalent series resistance (ESR), which makes the capacitors particularly suitable for high frequency applications.

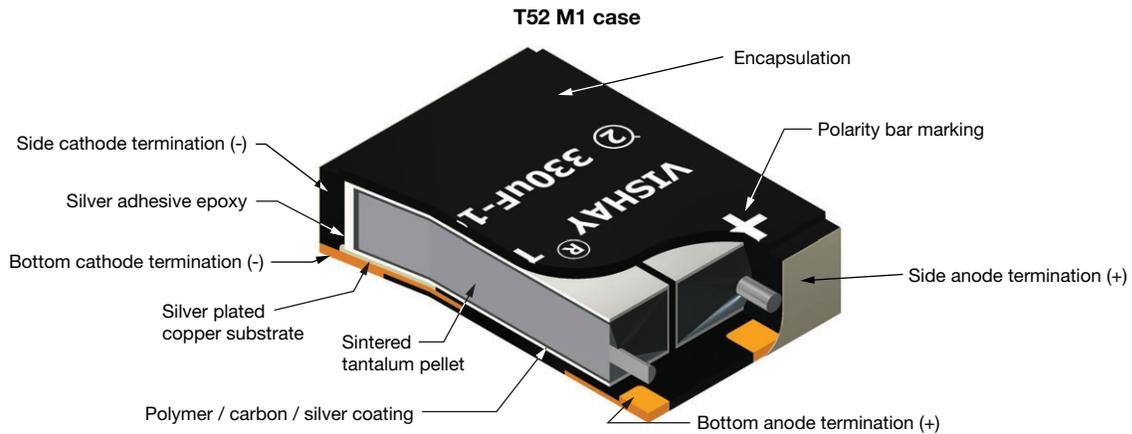
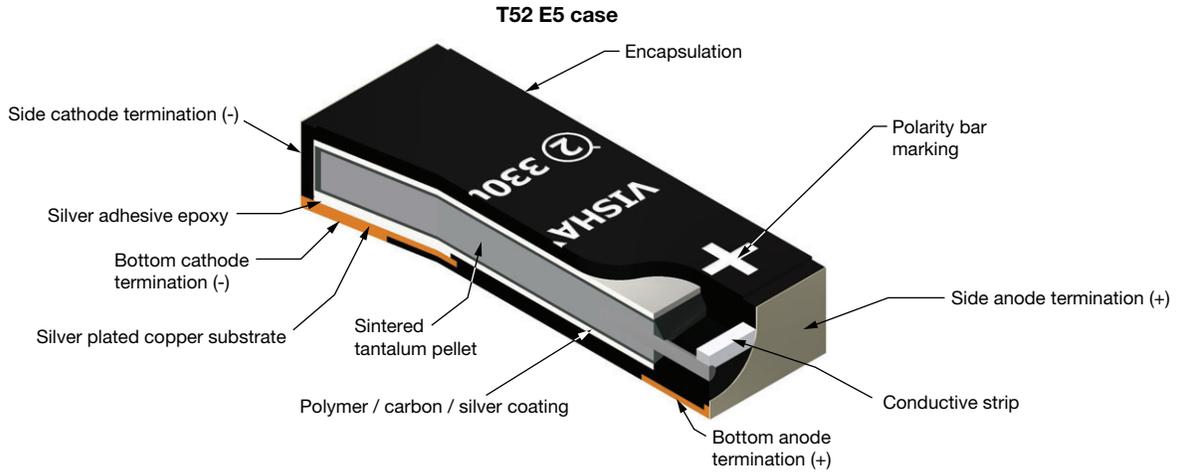
TANTALUM CAPACITOR WITH POLYMER CATHODE TYPE T50 / T51 / T55 / T56 / 04051



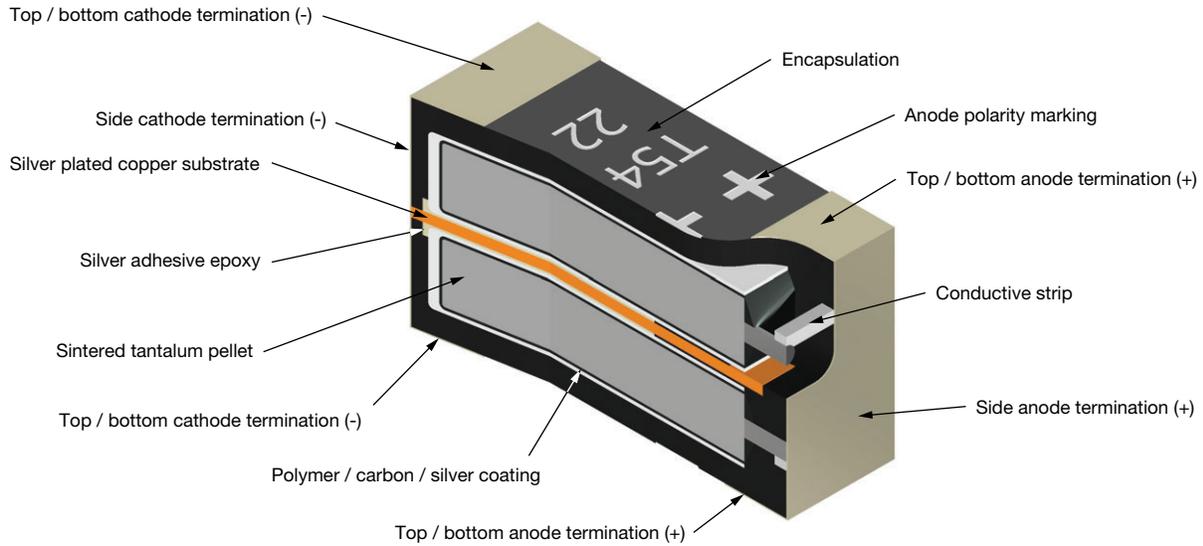
TANTALUM CAPACITOR WITH POLYMER CATHODE TYPE T58



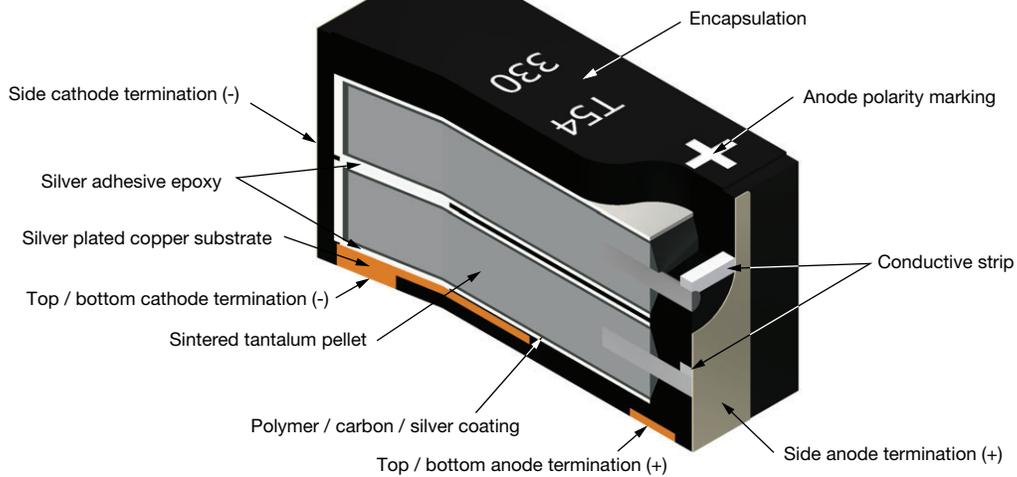
TANTALUM CAPACITOR WITH POLYMER CATHODE TYPE T52



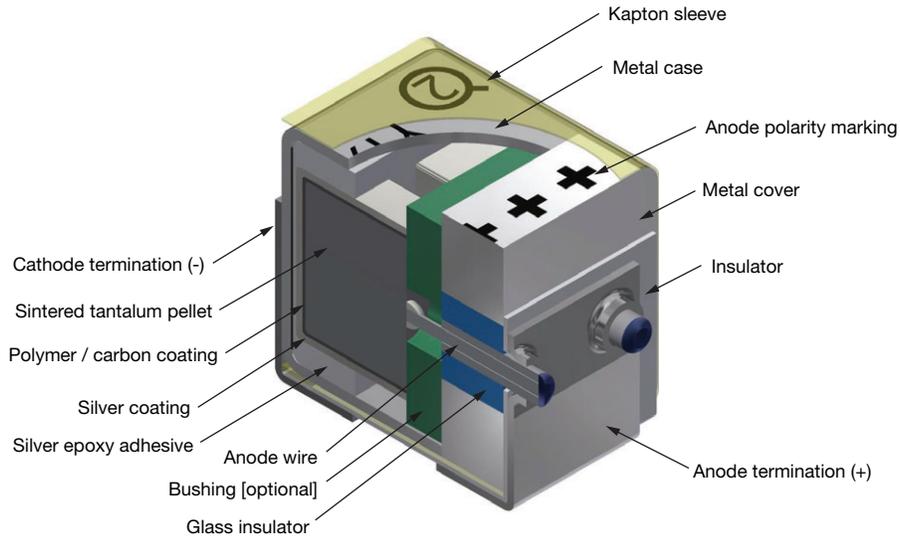
TANTALUM CAPACITOR WITH POLYMER CATHODE TYPE T54 / T59 / 20021



T54 EL case



HERMETICALLY SEALED TANTALUM CAPACITOR WITH POLYMER CATHODE TYPE T27



POLYMER CAPACITORS - METAL CASE, HERMETICALLY SEALED

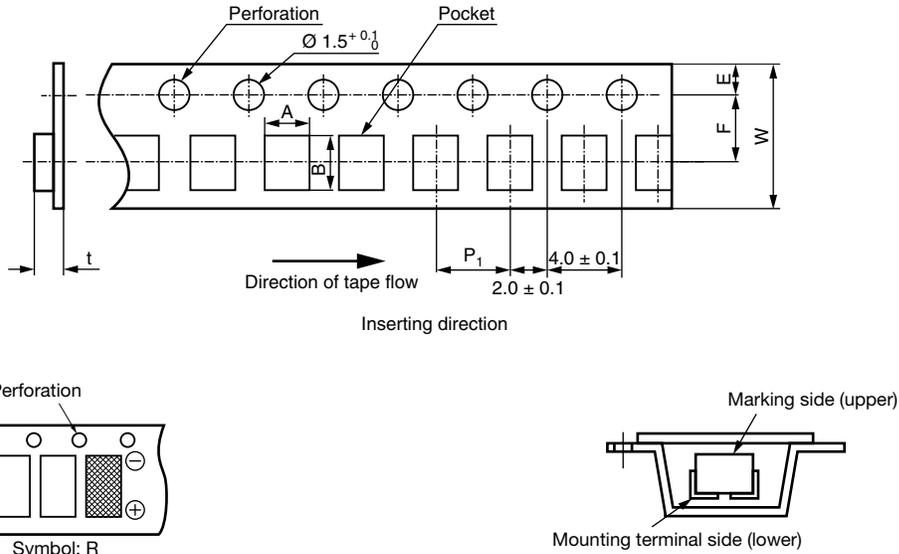
SERIES	T27
PRODUCT IMAGE	
TYPE	VPolyTan™ hermetically sealed polymer surface-mount chip capacitors, low ESR
FEATURES	Hermetically sealed in metal case, low ESR / low DCL, hi-rel. processing
TEMPERATURE RANGE	-55 °C to +125 °C
CAPACITANCE RANGE	15 μF to 470 μF
VOLTAGE RANGE	16 V to 75 V
CAPACITANCE TOLERANCE	± 20 %
LEAKAGE CURRENT	0.05 CV
DISSIPATION FACTOR	12 %
ESR	25 mΩ to 100 mΩ
CASE SIZES	D
TERMINATION FINISH	100 % tin; tin / lead

POLYMER CAPACITORS - MOLDED CASE		
SERIES	T50, T51, T55, T56	04051
PRODUCT IMAGE		
TYPE	VPolyTan™, molded case, high performance polymer	VPolyTan™, molded case, high performance polymer
FEATURES	High performance	High performance
TEMPERATURE RANGE	-55 °C to +105 °C / +125 °C	-55 °C to +125 °C (above +105 °C, voltage derating is required)
CAPACITANCE RANGE	3.3 µF to 1000 µF	4.7 µF to 680 µF
VOLTAGE RANGE	2.5 V to 63 V	2.5 V to 63 V
CAPACITANCE TOLERANCE	± 20 %	± 10 %, ± 20 %
LEAKAGE CURRENT	0.1 CV	0.1 CV
DISSIPATION FACTOR	8 % to 10 %	8 % to 10 %
ESR	6 mΩ to 500 mΩ	25 mΩ to 125 mΩ
CASE SIZES	J, P, A, T, B, Z, V, D, C	B, D
TERMINATION FINISH	Cases J, P, C: 100 % tin Case A, T, B, Z, V, D: Ni / Pd / Au	All cases: tin / lead (SnPb)

POLYMER CAPACITORS - LEADFRAMELESS MOLDED CASE					
SERIES	T52	T58	T59	T54	20021
PRODUCT IMAGE					
TYPE	vPolyTan™ polymer surface mount chip capacitors, low profile, leadframeless molded type	vPolyTan™ polymer surface mount chip capacitors, compact, leadframeless molded type	vPolyTan™ polymer surface mount chip capacitors, low ESR, leadframeless molded type	vPolyTan™ polymer surface mount chip capacitors, low ESR, leadframeless molded type, hi-rel commercial off-the-shelf (COTS)	vPolyTan™ polymer surface mount chip capacitors, low ESR, leadframeless molded type, DLA approved
FEATURES	Low profile	Small case size	Multinode	Hi-rel COTS, multinode	Multinode
TEMPERATURE RANGE	-55 °C to +105 °C	-55 °C to +105 °C	-55 °C to +125 °C	-55 °C to +125 °C	-55 °C to +125 °C
CAPACITANCE RANGE	47 µF to 470 µF	1 µF to 100 µF	15 µF to 470 µF	15 µF to 470 µF (discrete capacitors) 30 µF to 2800 µF (stacked capacitors)	15 µF to 470 µF (discrete capacitors) 30 µF to 2800 µF (stacked capacitors)
VOLTAGE RANGE	10 V to 35 V	6.3 V to 35 V	16 V to 75 V	16 V to 75 V	16 V to 75 V
CAPACITANCE TOLERANCE	± 20 %	± 20 %	± 10 %, ± 20 %	± 20 %	± 20 %
LEAKAGE CURRENT	0.1 CV				
DISSIPATION FACTOR	10 %	8 % to 14 %	10 % to 12 %	10 % to 12 %	10 % to 12 %
ESR	40 mΩ to 200 mΩ	90 mΩ to 500 mΩ	20 mΩ to 150 mΩ	5 mΩ to 150 mΩ	5 mΩ to 150 mΩ
CASE SIZES	E5, M1, M9, B2	MM, W0, W9, A0, BB	EE, EL	EE, EL, E2, E3, E4, E6, 3E, 6E	EE, E2, E3, E4, E6, 3E, 6E
TERMINATION	100 % tin		100 % tin; tin / lead		Tin / lead

MOLDED CAPACITORS, T50 / T51 / T55 / T56 / 04051 TYPES

PLASTIC TAPE SIZE DIMENSIONS in millimeters

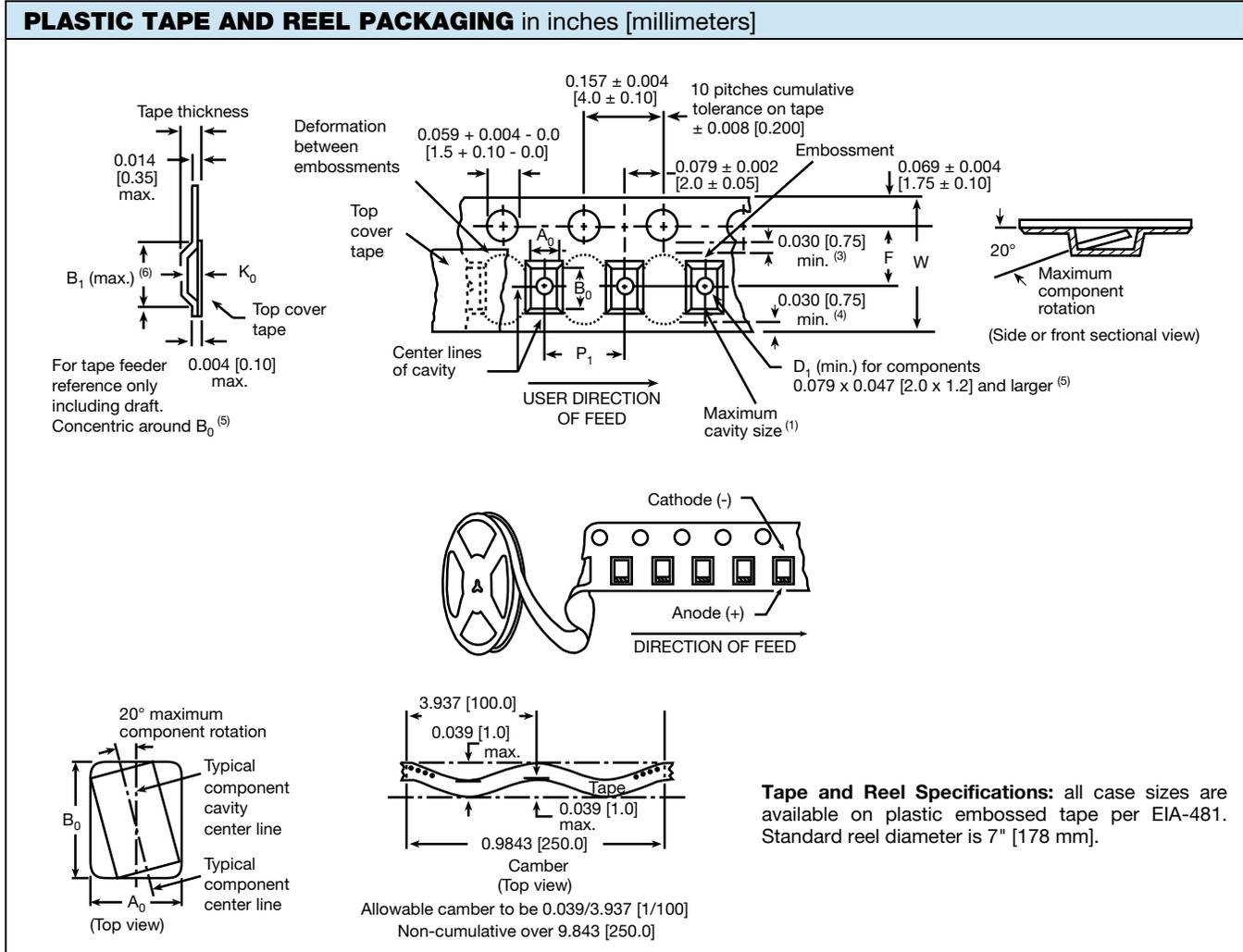


CASE CODE	A ± 0.2	B ± 0.2	W ± 0.3	F ± 0.1	E ± 0.1	P ₁ ± 0.1	t _{max.}
J	1.0	1.8	8.0	3.5	1.75	4.0	1.3
P	1.4	2.2	8.0	3.5	1.75	4.0	1.6
A	1.9	3.5	8.0	3.5	1.75	4.0	2.5
T	3.1	3.8	8.0	3.5	1.75	4.0	1.7
B	3.1	3.8	8.0	3.5	1.75	4.0	2.5
C	3.7	6.3	12.0	5.5	1.75	8.0	3.1
Z	4.8	7.7	12.0	5.5	1.75	8.0	2.6
V	4.8	7.7	12.0	5.5	1.75	8.0	2.6
D	4.8	7.7	12.0	5.5	1.75	8.0	3.4

Note

- A reel diameter of 330 mm is also applicable

LEADFRAMELESS MOLDED CAPACITORS, ALL TYPES



PACKING AND STORAGE

Polymer capacitors meet moisture sensitivity level rating (MSL) of 3 or 4 as specified in IPC/JEDEC® J-STD-020 and are dry packaged in moisture barrier bags (MBB) per J-STD-033. MSL for each particular family is defined in the datasheet - either in “Features” section or “Standard Ratings” table. Level 3 specifies a floor life (out of bag) of 168 hours and level 4 specifies a floor life of 72 hours at 30 °C maximum and 60 % relative humidity (RH). Unused capacitors should be re-sealed in the MBB with fresh desiccant. A moisture strip (humidity indicator card) is included in the bag to assure dryness. To remove excess moisture, capacitors can be dried at 40 °C (standard “dry box” conditions).

For detailed recommendations please refer to J-STD-033.

RECOMMENDED REFLOW PROFILES		
Vishay recommends no more than 3 cycles of reflow in accordance with J-STD-020.		
PROFILE FEATURE	SnPb EUTECTIC ASSEMBLY	LEAD (Pb)-FREE ASSEMBLY
PREHEAT AND SOAK		
Temperature min. ($T_{Smin.}$)	100 °C	150 °C
Temperature max. ($T_{Smax.}$)	150 °C	200 °C
Time (t_s) from ($T_{Smin.}$ to $T_{Smax.}$)	60 s to 120 s	60 s to 120 s
RAMP UP		
Ramp-up rate (T_L to T_p)	3 °C/s maximum	
Liquidus temperature (T_L)	183 °C	217 °C
Time (t_L) maintained above T_L	60 s to 150 s	
Peak package body temperature (T_p) max.	Depends on type and case - see table below	
Time (t_p) within 5 °C of the peak max. temperature	20 s	5 s ⁽¹⁾
RAMP DOWN		
Ramp-down rate (T_p to T_L)	6 °C/s maximum	
Time from 25 °C to peak temperature	6 min maximum	8 min maximum

Note

⁽¹⁾ For T27, lead (Pb)-free capacitors $t_p = 30$ s

PEAK PACKAGE BODY TEMPERATURE (T _p) MAXIMUM			
TYPE	CASE CODE	PEAK PACKAGE BODY TEMPERATURE (T _p) MAX.	
		SnPb EUTECTIC ASSEMBLY	LEAD (Pb)-FREE ASSEMBLY
T27	D	220 °C	245 °C
T55	J, P, A, T, B, C, Z, V, D	n/a	260 °C
T52	E5, M1, M9, B2		260 °C
T58	MM, W9, W0, A0, BB		260 °C
T50	D		260 °C
T51	D, V		260 °C
T56	B, V		260 °C
T56	D		250 °C
T59	EE, EL		220 °C
T54	EL, 3E, 6E, EE, E2, E3, E4, E6	220 °C	250 °C
20021	3E, 6E, EE, E2, E3, E4, E6	220 °C	n/a
04051	D	220 °C	n/a
04051	B	235 °C	n/a
M327001	D	220 °C	n/a
M327001	B, C	235 °C	n/a

Notes

- T50, T51, T52, T55, T56 (B, V cases), and T58 capacitors are process sensitive.
PSL classification to JEDEC J-STD-075: R4G
- T54, T59, and T56 (D case) capacitors with 100 % tin termination are process sensitive.
PSL classification to JEDEC J-STD-075: R6G

MOLDED CAPACITORS, T50 / T51 / T55 / T56 / 04051 TYPES

PAD DIMENSIONS in millimeters						
CASE / DIMENSIONS	CAPACITOR SIZE		PAD DIMENSIONS			
	L	W	G (max.)	Z (min.)	X (min.)	Y (Ref.)
J	1.6	0.8	0.7	2.5	1.0	0.9
P	2.0	1.25	0.5	2.6	1.2	1.05
A	3.2	1.6	1.1	3.8	1.5	1.35
T / B	3.5	2.8	1.4	4.1	2.7	1.35
C	5.8	3.2	2.9	6.9	2.7	2.0
Z / V / D	7.3	4.3	4.1	8.2	2.9	2.05

LEADFRAMELESS MOLDED CAPACITORS T52 / T58

PAD DIMENSIONS in inches [millimeters]					
FAMILY	CASE CODE	A (NOM.)	B (MIN.)	C (NOM.)	D (MIN.)
T52	E5	0.094 [2.40]	0.077 [1.95]	0.180 [4.57]	0.333 [8.46]
	M1, M9	0.178 [4.52]	0.098 [2.48]	0.138 [3.50]	0.333 [8.46]
	B2	0.081 [2.06]	0.057 [1.44]	0.070 [1.77]	0.183 [4.64]
T58	MM	0.024 [0.61]	0.027 [0.70]	0.025 [0.64]	0.080 [2.03]
	W0, W9	0.035 [0.89]	0.029 [0.74]	0.041 [1.05]	0.099 [2.52]
	A0	0.047 [1.19]	0.042 [1.06]	0.065 [1.65]	0.148 [3.76]
	BB	0.094 [2.39]	0.044 [1.11]	0.072 [1.82]	0.159 [4.03]

LEADFRAMELESS MOLDED CAPACITORS T59 / T54 / 20021

PAD DIMENSIONS in inches [millimeters]					
FAMILY	CASE CODE	A (NOM.)	B (MIN.)	C (NOM.)	D (MIN.)
T59 / T54	EE	0.209 [5.30]	0.098 [2.50]	0.169 [4.30]	0.366 [9.30]
	EL	0.098 [2.50]	0.098 [2.50]	0.169 [4.30]	0.366 [9.30]
T54	E2 / E3	0.128 [3.24]	0.120 [3.04]	0.154 [3.92]	0.394 [10.0]
	E4 / E6	0.301 [7.64]	0.120 [3.04]	0.154 [3.92]	0.394 [10.0]
	3E	0.482 [12.24]	0.120 [3.04]	0.154 [3.92]	0.394 [10.0]
	6E	0.482 [12.24]	0.120 [3.04]	0.154 [3.92]	0.394 [10.0]
20021	EE	0.209 [5.30]	0.098 [2.50]	0.169 [4.30]	0.366 [9.30]

HERMETICALLY SEALED CAPACITOR T27 TYPE

PAD DIMENSIONS in inches [millimeters]				
CASE CODE	A (MIN.)	B (NOM.)	C (NOM.)	D (NOM.)
D	0.295 [7.50]	0.138 [3.50]	0.100 [2.50]	0.374 [9.50]

GUIDE TO APPLICATION

- AC Ripple Current:** the maximum allowable ripple current shall be determined from the formula:

$$I_{RMS} = \sqrt{\frac{P}{R_{ESR}}}$$

where,

P = power dissipation in W at +45 °C as given in the tables in the product datasheets.

R_{ESR} = the capacitor equivalent series resistance at the specified frequency.

- AC Ripple Voltage:** the maximum allowable ripple voltage shall be determined from the formula:

$$V_{RMS} = Z \sqrt{\frac{P}{R_{ESR}}}$$

or, from the formula:

$$V_{RMS} = I_{RMS} \times Z$$

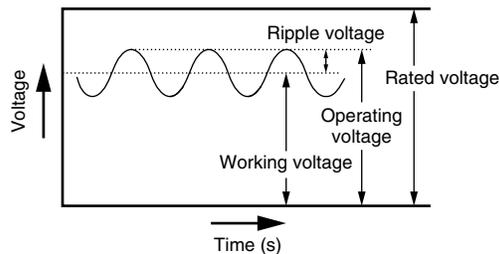
where,

P = power dissipation in W at +45 °C as given in the tables in the product datasheets.

R_{ESR} = The capacitor equivalent series resistance at the specified frequency.

Z = The capacitor impedance at the specified frequency.

- The tantalum capacitors must be used in such a condition that the sum of the working voltage and ripple voltage peak values does not exceed the rated voltage as shown in figure below.



- Temperature Derating:** power dissipation is affected by the heat sinking capability of the mounting surface. If these capacitors are to be operated at temperatures above +45 °C, the permissible ripple current (or voltage) shall be calculated using the derating coefficient as shown in the table below:

MAXIMUM RIPPLE CURRENT TEMPERATURE DERATING FACTOR	
≤ 45 °C	1.0
55 °C	0.8
85 °C	0.6
105 °C	0.4
125 °C	0.25

- Reverse Voltage:** the capacitors are not intended for use with reverse voltage applied. However, they are capable of withstanding momentary reverse voltage peaks, which must not exceed the following values:

At 25 °C: 10 % of the rated voltage or 1 V, whichever is smaller.

At 85 °C: 5 % of the rated voltage or 0.5 V, whichever is smaller.

At 105 °C: 3 % of the rated voltage or 0.3 V, whichever is smaller.

- Mounting Precautions:**

- Soldering:** capacitors can be attached by conventional soldering techniques; vapor phase, convection reflow, infrared reflow, wave soldering, and hot plate methods. The soldering profile charts show recommended time / temperature conditions for soldering. Preheating is recommended. The recommended maximum ramp rate is 3 °C per second. Attachment with a soldering iron is not recommended due to the difficulty of controlling temperature and time at temperature. The soldering iron must never come in contact with the capacitor. For details see www.vishay.com/doc?40214.

- Limit Pressure on Capacitor Installation with Mounter:** pressure must not exceed 4.9 N with a tool end diameter of 1.5 mm when applied to the capacitors using an absorber, centering tweezers, or similar (maximum permitted pressurization time: 5 s). An excessively low absorber setting position would result in not only the application of undue force to the capacitors but capacitor and other component scattering, circuit board wiring breakage, and / or cracking as well, particularly when the capacitors are mounted together with other chips having a height of 1 mm or less.

- Flux Selection**

- Select a flux that contains a minimum of chlorine and amine.

- After flux use, the chlorine and amine in the flux remain must be removed.

- Cleaning After Mounting:** the following solvents are usable when cleaning the capacitors after mounting. Never use a highly active solvent.

- Halogen organic solvent (HCFC225, etc.)
- Alcoholic solvent (IPA, ethanol, etc.)
- Petroleum solvent, alkali saponifying agent, water, etc.

Circuit board cleaning must be conducted at a temperature of not higher than 50 °C and for an immersion time of not longer than 30 minutes. When an ultrasonic cleaning method is used, cleaning must be conducted at a frequency of 48 kHz or lower, at an vibrator output of 0.02 W/cm³, at a temperature of not higher than 40 °C, and for a time of 5 minutes or shorter.

Notes

- Care must be exercised in cleaning process so that the mounted capacitor will not come into contact with any cleaned object or the like or will not get rubbed by a stiff brush or similar. If such precautions are not taken particularly when the ultrasonic cleaning method is employed, terminal breakage may occur
- When performing ultrasonic cleaning under conditions other than stated above, conduct adequate advance checkout



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